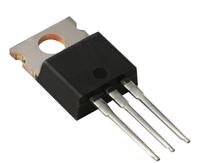
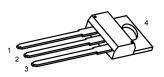
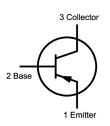
# Transistor General Purpose





RoHS

**Compliant** 



## Description:

A Silicon epitaxial PNP Darlington transistor in a TO-220 type Case designed for general-purpose amplifier and Low speed switching circuits.

### Features:

• High DC Current Gain

**Maximum Ratings:** 

- Collector-Emitter Sustaining Voltage V<sub>CEO(SUS)</sub>=100V Min.
- Monolithic Construction With Built-in Base-Emitter Shunt Resistors

#### Characteristic Symbol Unit Rating Collector-Emitter Voltage V<sub>CEO</sub> 80 Collector-Base Voltage V $V_{CB}$ Emitter-Base Voltage V<sub>EB</sub> 5 Collector Current -Continuous 8 $I_{C}$ А -Peak 16 **Base Current** 120 $I_{B}$ mΑ Total Device Dissipation -( $T_C = +25^{\circ}C$ ), 75 Derate Above 25°C 0.6 W $P_{D}$ W/°C Total Device Dissipation -( $T_A = +25^{\circ}C$ ), 2.2 Derate Above 25°C 0.0175 **Operating Junction Temperature Range** $T_{\perp}$ °C -65 to +150 Storage Temperature Range, T<sub>stq</sub> R<sub>thJC</sub> Thermal Resistance, Junction-to-Case, 1.67 °C/W Thermal Resistance, Junction-to-Ambient, R<sub>thJA</sub> 57

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#### Pin Configuration: 1. Emitter

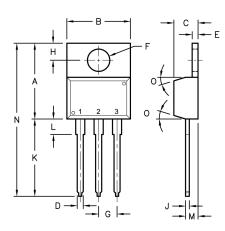
- 2. Base
- 3. Collector

#### Electrical Characteristics: (T<sub>c</sub> = +25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Max	Unit
Collector-Emitter Saturation Voltage	V <sub>CEO(SUS)</sub>	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0, Note 1	80	-	V
	I <sub>CEO</sub>	V <sub>CE</sub> = 80V, I <sub>B</sub> = 0		20	
Collector Cutoff Current	I <sub>CEX</sub>	$V_{CE}$ = 80V, $V_{BE(off)}$ = -1.5V			μA
		$V_{CE} = 80V, V_{BE (off)} = -1.5V, T_{C} = +150^{\circ}C$	-	200	
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0		2	mA
On Characteristics					
DC Current Gain	h <sub>FE</sub>	$V_{CE} = 4V, I_{C} = 4A$	1,000	20,000	
		V <sub>CE</sub> = 4V, I <sub>C</sub> = 8A	100	-	-
Collector Emitter Saturation Voltage	V <sub>CE(Sat)</sub>	I <sub>C</sub> = 4A, I <sub>B</sub> = 16mA		2	
Collector-Emitter Saturation Voltage		I <sub>C</sub> = 8A, I <sub>B</sub> = 80mA	-	4	V
Base-Emitter ON Voltage	V <sub>BE(on)</sub>	$V_{CE} = 4V, I_{C} = 4A$	2.8		]
Dunamic Characteristics					
	h <sub>fe</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 1A, f = 1MHz	4		
Small-Signal Current Gain	h <sub>fe</sub>	V <sub>CE</sub> = 4V, I <sub>C</sub> = 3A, f = 1kHz	300		-
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10V, I <sub>F</sub> = 0, f = .1MHz		300	pF

#### Note:

1. Pulse Width = 300 $\mu$ s, Duty Cycle  $\leq 2\%$ 



#### **Pin Configuration:**

- 1. Emitter
- 2. Base
- 3. Collector

Dimension	Min.	Max.	
A	14.42	16.51	
В	9.63	10.67	
С	3.56	4.83	
D	-	0.9	
E	1.15	1.4	
F	3.75	3.88	
G	2.29	2.79	
Н	2.54	3.43	
J	-	0.56	
K	12.7	14.73	
L	2.8	4.07	
М	2.03	2.92	
N	-	31.24	
0	7°		
Dimensions : Millimetres			

Part	Number	Table
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Description	Part Number		
Transistor, PNP, 8A, 80V, TO-220	2N6124		

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